

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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MBRH20030(R)L

Low V_F Silicon Power Schottky Diode

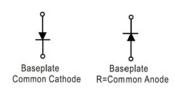
 $V_{RRM} = 30 V$

 $I_{F(AV)} = 200 A$

Features

- · High Surge Capability
- Type 30 V V_{RRM}
- Not ESD Sensitive











Maximum ratings, at $T_j = 25$ °C, unless otherwise specified ("R" devices have leads reversed)

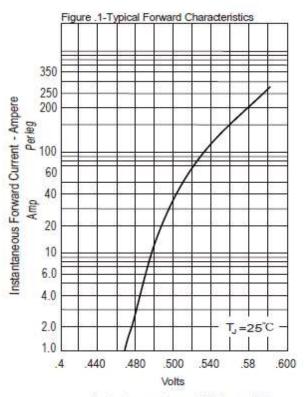
Parameter		Symbol	Conditions	MBRH20030(R)L	Unit
Maximum recurrent peak	reverse voltage	V_{RRM}		30	V
Maximum RMS voltage		V_{RMS}		21	V
Maximum DC blocking vo	Itage	V_{DC}		30	V
Operating temperature		Tj		-55 to 150	°C
Storage temperature		T _{stg}		-55 to 150	°C

Electrical characteristics, at Tj = 25 °C, unless otherwise specified

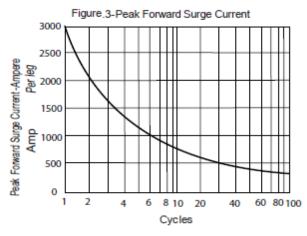
Parameter	Symbol	Conditions	MBRH20030(R)L	Unit
Average forward current	I _{F(AV)}	T _C = 100 °C	200	Α
Peak forward surge current	I _{FSM}	t_p = 8.3 ms, half sine	3000	Α
Maximum instantaneous forward voltage	V _F	I _{FM} = 200 A, Tj = 25 °C	0.58	V
Maximum instantaneous reverse		T _j = 25 °C	3	mA
current at rated DC blocking voltage	I _R	T _j = 100 °C	150	
Thermal characteristics				
Maximum thermal resistance, junction - case	R _{eJC}		0.35	°C/W



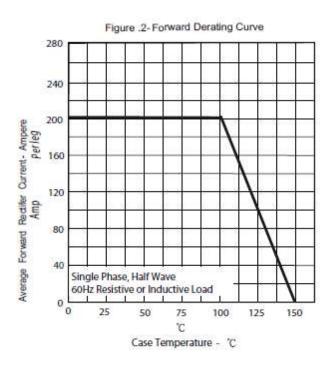


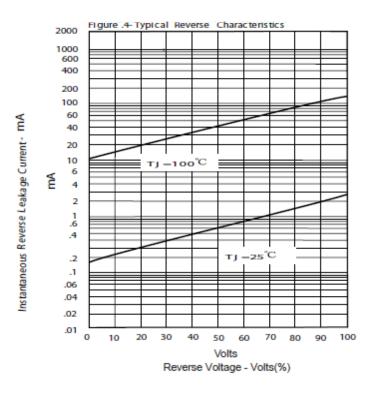


Instantaneous Forward Voltage - Volts



Number Of Cycles At 60Hz - Cycles

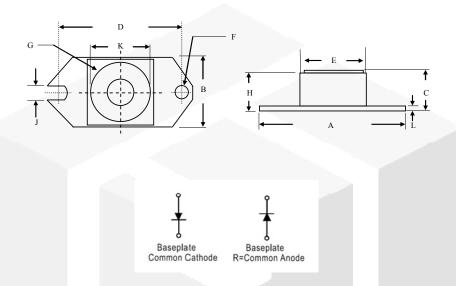






Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



	Inches		Millimeters		
	Min	Max	Min	Max	
A	1.515	1.560	38.48	39.62	
В	0.725	0.775	18.42	19.69	
С	0.595	0.625	15.11	15.88	
D	1.182	1.192	30.02	30.28	
Е	0.736	0.744	18.70	18.90	
F	0.152	0.160	3.86	4.061	
G	1/4–20 UNC				
Н	0.540	0.580	13.72	14.73	
J	0.156	0.160	3.96	4.06	
K	0.480	0.492	12.20	12.50	
L	0.120	0.130	3.05	3.30	